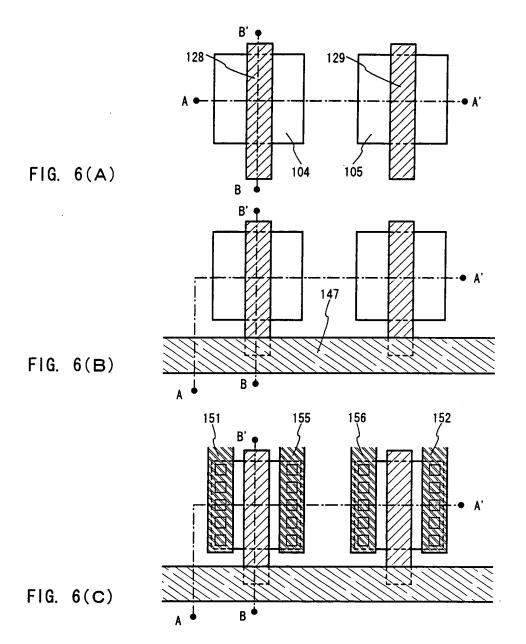
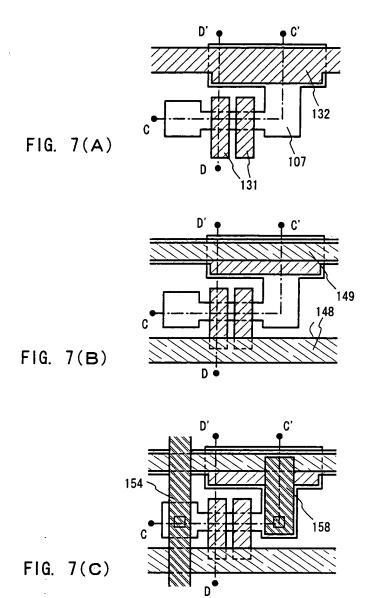


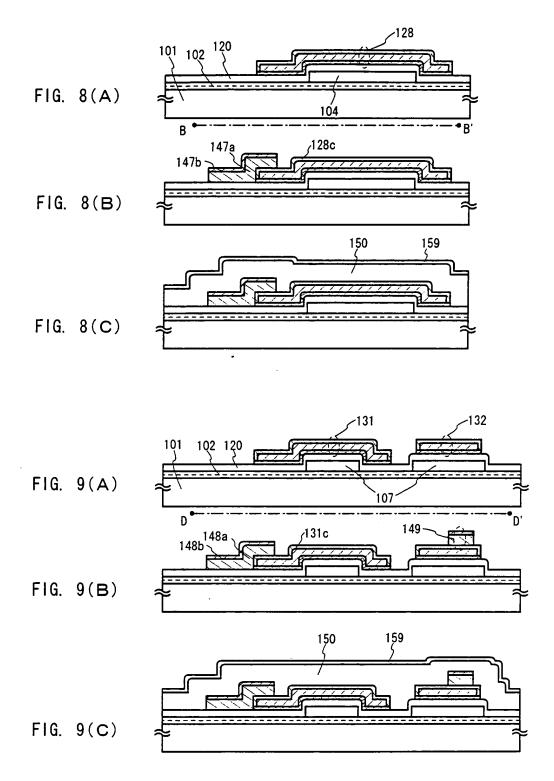
205: STORAGE CAPACITOR PIXEL PORTION 204: PIXEL TFT 161 FORMING STEP OF RESIN FILM/FORMING STEP OF CONTACT HOLE/FORMING STEP OF PIXEL ELECTRODE 154 163 159 196 148 203: SECOND N CHANNEL TFT SAMPLING CIRCUIT 157 8 153 202: FIRST N CHANNEL TFT CMOS CIRCUIT

DRIVING CIRCUIT 201: P CHANNL TFT 155 2

F16. 5







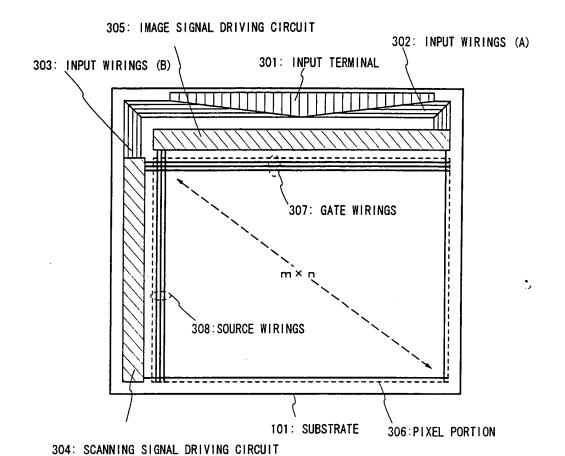
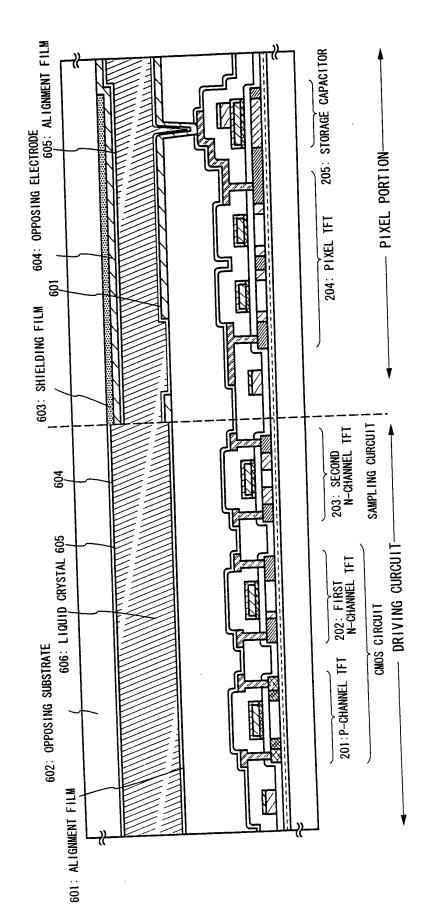


FIG. 10



F1G. 11

•

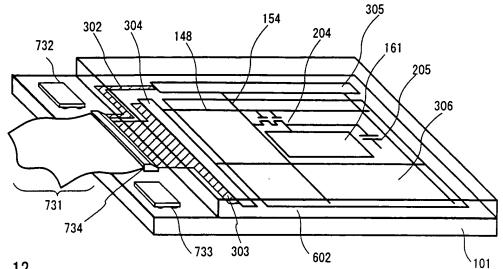


FIG. 12

101: SUBSTRATE
306: PIXEL PORTION
302. 303: INPUT WIRINGS
304: SCANNING SIGNAL DRIVING CIRCUIT
305: IMAGE SIGNAL DRIVING CIRCUIT
731: FPC
732. 733: IC CHIP
734: external I/O terminal

204 : PIXEL TFT 148 : GATE WIRINGS 154 : SOURCE WIRINGS 161 : PIXEL ELECTRODE 205 : STORAGE CAPACITOR

602 : OPPOSING SUBSTRATE

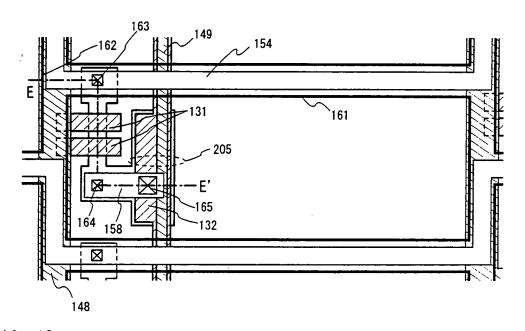
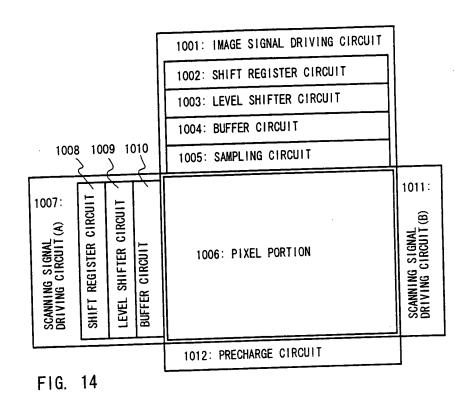
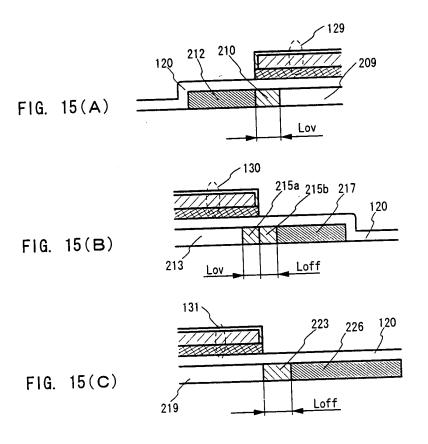
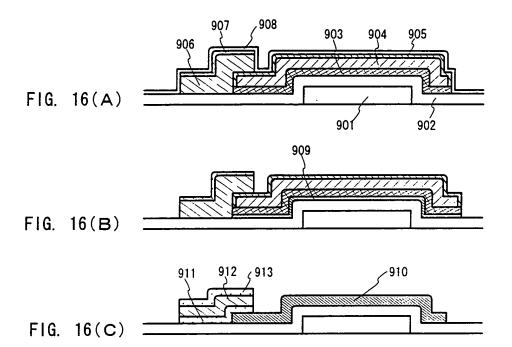


FIG. 13







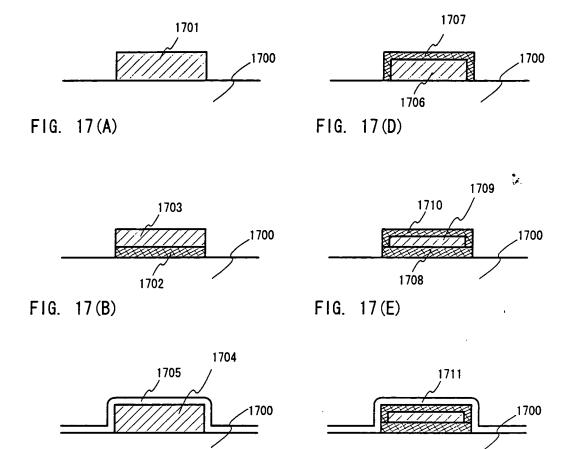
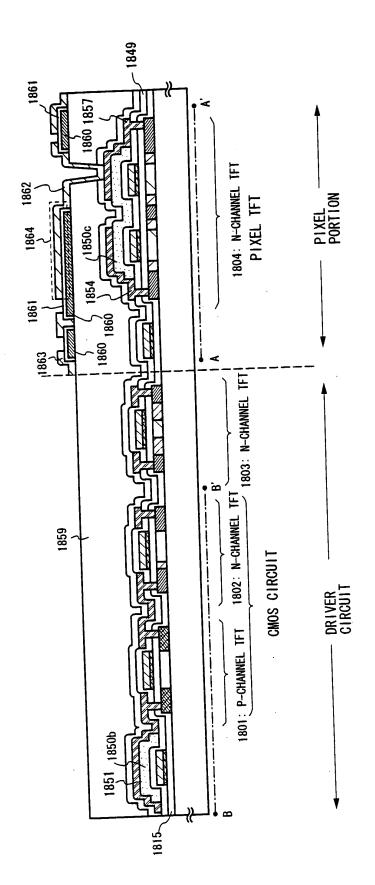
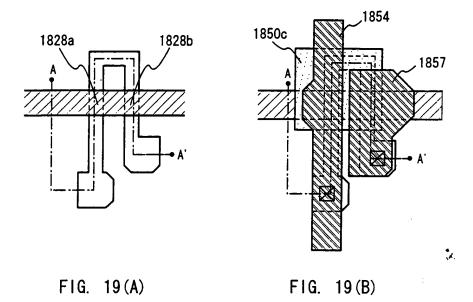


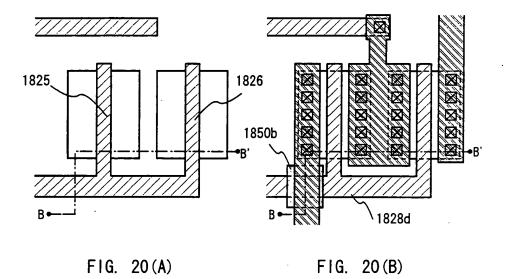
FIG. 17(F)

FIG. 17(C)

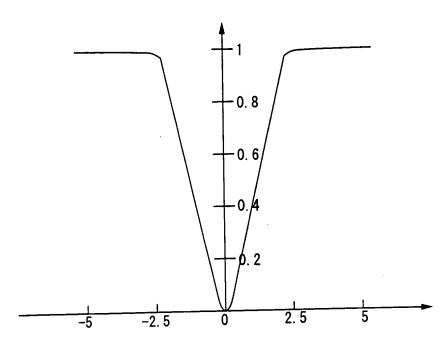


F1G. 18



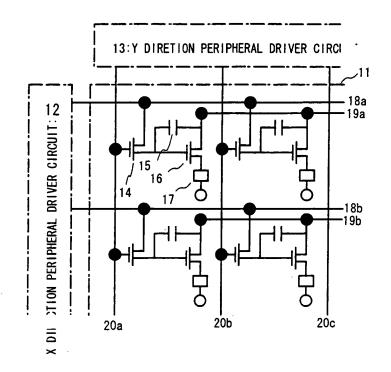






APPLIED VOLTAGE (V)

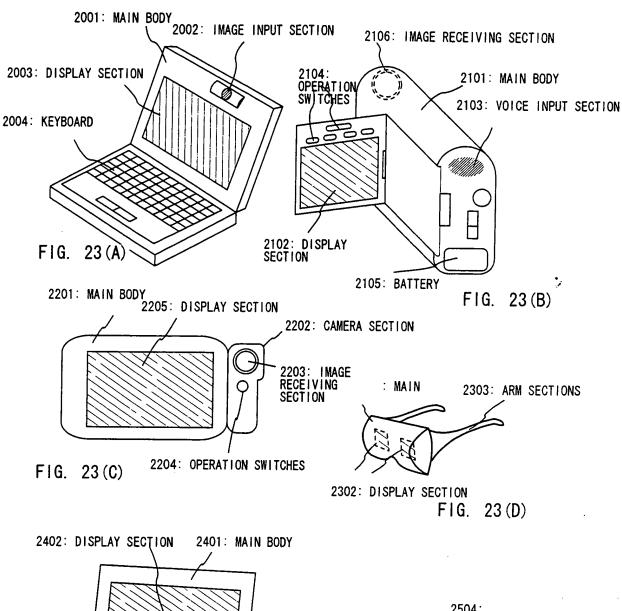
FIG. 21

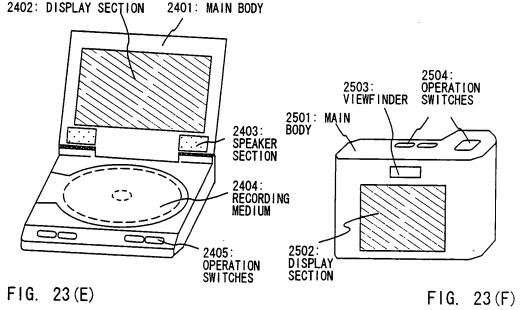


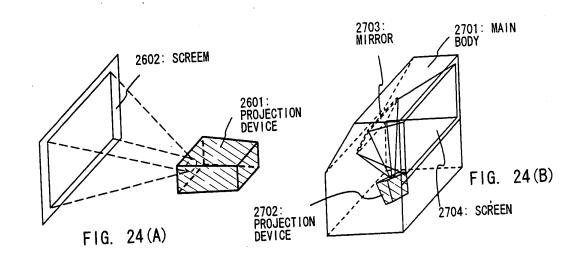
11: PIXEL PORTION
12: X DIRECTION PERIPHERAL DRIVER CIRCUIT
13: Y DIRETION PERIPHERAL DRIVER CIRCUIT

13: Y DIRETION PERIPHERAL DRIVER CIRCUIT
14: SWITCHING TFT
15: STORAGE CAPACITOR
16: CURRENT CONTROLLING TFT
17: ORGANIC EL ELEMENT
18A, 18B: X-DIRECTION SIGNAL LINES
19A, 19B: POWER SUPPLY LINES
20A, 20B, 20C: Y-DIRECTION SIGNAL LINES

FIG. 22







TOWARD SCREEN

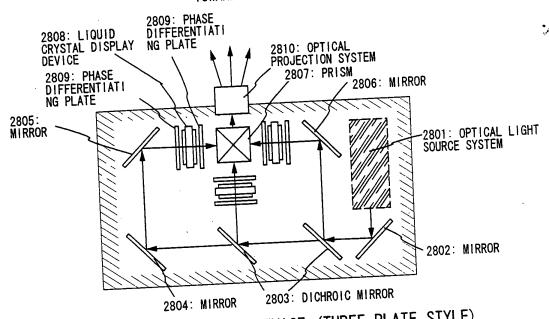


FIG. 24(C) PROJECTION DEVICE (THREE-PLATE STYLE)

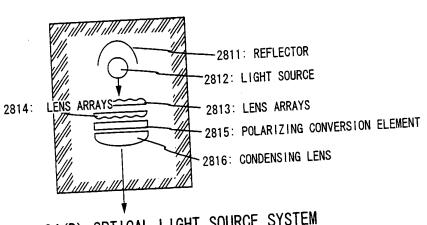


FIG. 24(D) OPTICAL LIGHT SOURCE SYSTEM

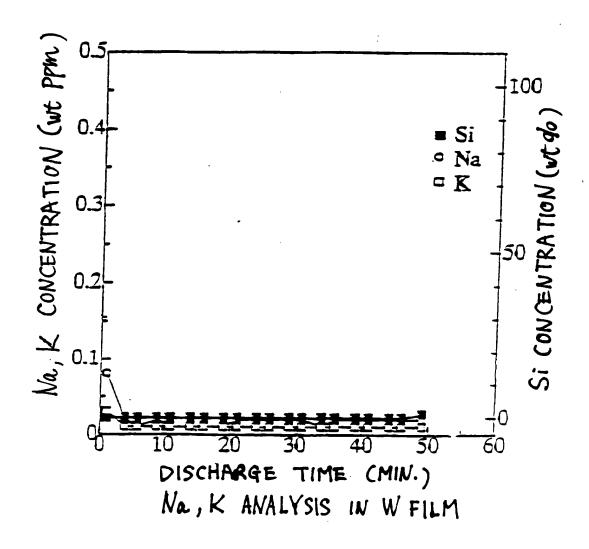
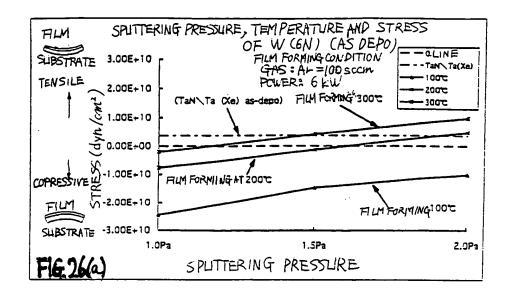
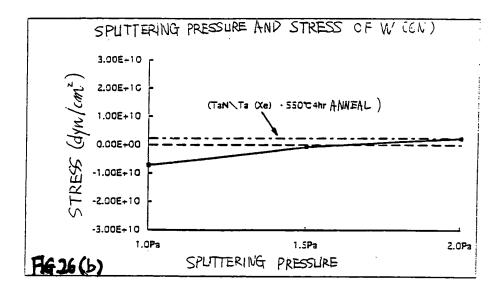
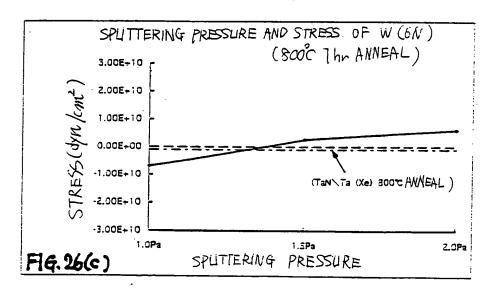
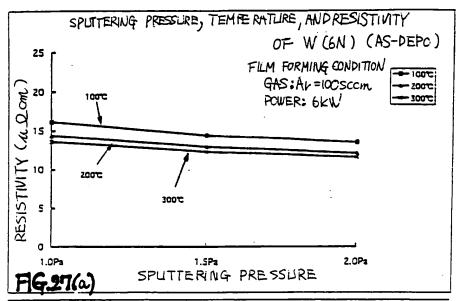


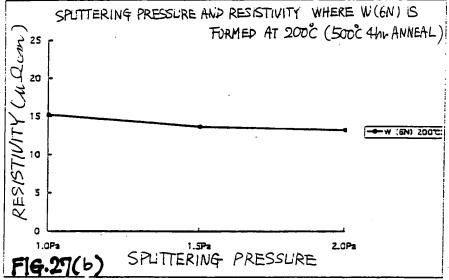
FIG.25

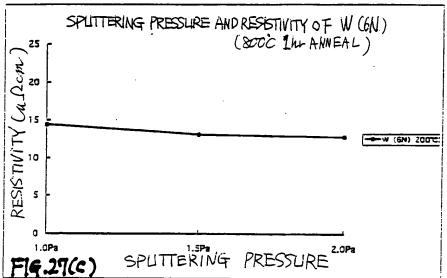












įλ.

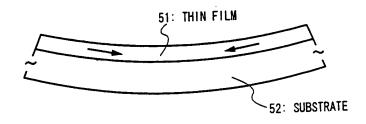


FIG. 28(A) TENSILE STRESS

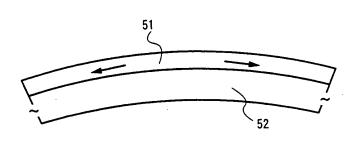


FIG. 28(B) COMPRESSIVE STRESS

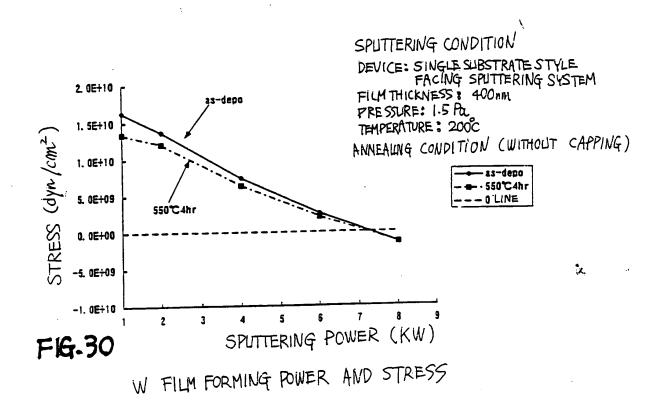
THE NUMBER OF CONTACT HOLE: 50
CONTACT SURFACE AREA: 20 x 21 µm

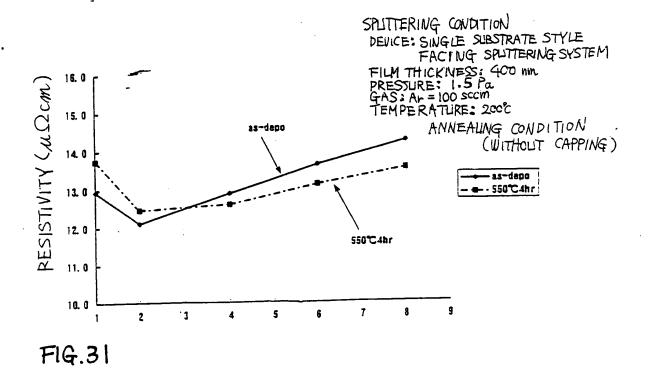
62: ELECTRODE (A1-Si)

61: ELECTRODE (WN/W or TaN/Ta)

60: SUBSTRATE

FIG. 29





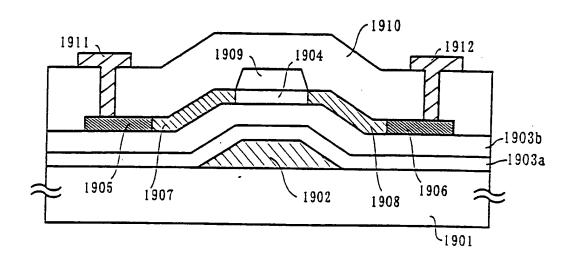


FIG. 32